Sulfur-enhanced dynamics of coinage metal(111) surfaces: Step edges vs terraces as locations for metal-sulfur complex formation

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\textbf{ABSTRACT}

The propensity of trace amounts of sulfur adsorbed on coinage metal(111) surfaces to dramatically enhance surface dynamics has been demonstrated by STM observations of accelerated 2D island decay for Cu and Ag. It is generally accepted that this enhancement is due to the formation of adsorbed metal-sulfur complexes which facilitate surface mass transport of the metal. These complexes were originally proposed to form on terraces following extraction of metal atoms from step edges and subsequent combination with sulfur on the terraces. However, even when

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thermodynamically feasible, this mechanism may not be kinetically viable for some complexes due to limited coupling of the complex concentration to the surface diffusion flux of metal atoms. Focusing on the case of Cu, we assess various scenarios where complexes are formed either on terraces or instead directly at step edges, the latter being a new paradigm. A new pathway is proposed for formation on terraces. A rich variety of structures incorporating S at step edges exist which could provide a viable source for complexes, at least from a thermodynamic perspective. However, it is necessary to also assess the activation barrier for complex formation and detachment from step edges. This is facilitated by nudged-elastic-band analysis of the minimum energy path for this process utilizing machine-learning (ML) derived potentials based on DFT energetics for the metal-sulfur system.

I. INTRODUCTION

Coarsening or ripening of non-equilibrium nanostructured systems is a generic phenomenon related to the tendency of these systems to reduce the energy penalty associated with a high density of interfaces by increasing the characteristic length scale of structures.\textsuperscript{1} One broad class of such systems involves arrays of metal nanoclusters (NCs) either in solution\textsuperscript{2} or supported on surfaces,\textsuperscript{3,5} where the above mentioned energy penalty can be regarded as associated with broken bonds at the periphery of the NCs. In this case, coarsening involves a decrease in time of the number (or density) of such NCs, and a corresponding increase in their mean size, consistent with mass
conservation. A classic mechanism of coarsening is Ostwald Ripening (OR) wherein mass is transferred from smaller than average to larger than average NCs, which results in the ultimate disappearance of the latter.\(^3\) A competing mechanism is NC or Particle Migration and Coalescence (PMC), also called Smoluchowski Ripening (SR),\(^5\) although the current contribution is focused on OR type processes.

Further restricting attention to supported metal nanoclusters on flat single-crystal surfaces, the default expectation is that OR under **pristine ultrahigh-vacuum conditions** will involve detachment of individual metal atoms from smaller NCs, followed by diffusion across the surface and attachment to larger NCs.\(^3\) There is much interest in the understanding of such OR (or SR) processes as they provide mechanisms for the degradation of the catalytic properties of 3D metal NCs supported on oxides or other substrates,\(^6\) noting that OR reduces the NC surface area and thus catalytic activity.

However, more fundamental and definitive studies of OR (and SR) have considered 2D metal NCs in metal homoepitaxial systems, where a combination of Scanning Tunneling Microscopy (STM) and high-level atomistic-level modeling can provide a detailed characterization and understanding of coarsening. The reader is referred to related reviews by the Thiel\(^5\) and Morgenstern\(^4\) groups.

Applications to catalysis motivate consideration of coarsening processes under **non-pristine “operating conditions”** where non-metallic chemisorbed species are present. In this context, we note the existence of a long-standing hypothesis in catalysis community that the degradation of supported 3D metal NC catalysts can be enhanced by the formation of volatile metal-oxygen complexes that facilitate metal mass transport, and thus enhance coarsening.\(^7,8\) However, rather than these more complex catalytic
systems, simpler metal homoepitaxial systems incorporating 2D metal NCs which will be considered here again offer the potential for more definitive analysis of such complex-facilitated mass transport and coarsening. In the context of these simpler systems, we also note recent general interest in refining the traditional view that metal surfaces are static or frozen during chemisorption or catalytic surface reaction, to instead account for their potentially fluxional nature. The above considerations of how chemisorbed species can enhance surface mass transport and coarsening should be regarded as contributing to this more general issue.

Henceforth, in this contribution, we will focus on the dynamics of metal homoepitaxial systems, which involve a low-index metal surface generally supporting 2D metal NCs and also including extended step edges, in the presence of chemisorbed chalcogens. Both serendipitous and controlled studies have revealed chalcogen-enhanced surface dynamics on coinage metal (M) surfaces, particularly on M(111) surfaces, but to some extent also on M(100) surfaces. Early observations involved accidental exposure to air of Au(111) by Peale and Cooper, and of Ag(100) by Layson and Thiel, where most likely oxygen induced enhancement. More specifically, these studies, and those described below, generally explored the rate of decay in size of 2D homoepitaxial metal NCs nearby extended step edges, observing much higher decay rates in the presence of chemisorbed chalcogen relative to the pristine chalcogen-free system. Subsequently, a detailed and controlled study was performed at Sandia National Laboratory by Ling et al. for S on Cu(111) revealing dramatic enhancement of NC decay rates even with trace amounts of S. Supporting DFT analysis suggested that mass transport was promoted by formation of Cu$_3$S$_3$ “trimer” complexes. This proposal
was later questioned with linear \( \text{CuS}_2 \) and \( \text{Cu}_2\text{S}_3 \) “hearts” being suggested as possible alternative mass transport agents.\(^{16}\) Similar dramatic enhancement for trace S on Ag(111) was observed by the Thiel group at Iowa State University, where \( \text{AgS}_2, \text{Ag}_3\text{S}_3, \) and other complexes were identified as possible was promoters of mass transport.\(^{17}\) In contrast, the Thiel group observed only moderate enhancement even for larger amounts of S on Au(111), where \( \text{AuS}_2 \) and \( \text{Au}_4\text{S}_4 \) were suggested as possible mass transport agents.\(^{18}\)

The rationalization for enhanced surface mass transport due to metal-sulfur complexes is that these have a low formation energy (i.e., a high volatility) relative to that of metal adatoms (which must be extracted from steps on the surface).\(^{13,15}\) Note that formation energies determine equilibrium adspecies concentrations on the surface. Specifically, lower complex formation energies lead to higher surface populations which can more than compensate for the anticipated lower mobility of the complex again relative to that of adatoms, thereby potentially enhancing mass transport.

In fact over the last decade, motivated by observations of enhanced coarsening, extensive studies have been performed by the Thiel group examining various aspects of behavior for S on the \( \{111\} \) surfaces of coinage metals (M)\(^{19-21}\) exploring all of M = Cu,\(^{16,22,23}\) M = Ag,\(^{17,24-28}\) and M = Au.\(^{18,29,30}\) One observation from these studies is the particular stability of linear S-M-S motifs, either as isolated MS\(_2\) complexes or as components of larger complexes. We comment on this feature further in this contribution. In addition, the Thiel group studied and compared behavior for \( \{111\} \) surfaces with that for S on the \( \{100\} \) surfaces of M = Cu,\(^{31}\) M = Ag,\(^{32,33}\) and M = Au.\(^{34}\) One conclusion from their experimental studies for these systems, aided by extensive
supporting DFT analysis, is as follows: complex formation is facile and dramatically enhances mass transport on Cu(111), and Ag(111) but only moderately on Au(111). In contrast, complex formation is less facile on the {100} surfaces of Cu and Ag where little enhancement is observed. Complex formation is predicted to be more facile on Au(100), but in this case, studies to assess the existence of S-enhanced surface dynamics have not yet been performed. Figure 1 displays pictures of the Thiel group graduate students involved in this series of work, together with that of their advisor.

We also note one unique feature of the Thiel group efforts, absent in studies by other groups, was the undertaking of ultra-low STM studies aiming to directly image by “freezing in” at 5 K, and at low S coverage, the isolated complexes implicated in enhanced mass transport. This effort was performed in collaboration with the groups of Maki Kawai and Yoosou Kim at RIKEN in Japan. Interpretation was facilitated detailed comparison of STM images with DFT generated images. Interestingly, Cu$_2$S$_3$ “hearts” and larger Cu$_m$S$_{m+1}$ concatenated chains (but not Cu$_3$S$_3$ “trimers”) were observed on Cu(111). Only relatively large complexes were observed on Ag(111), including Ag$_{16}$S$_{13}$, although fragments of these (such as linear AgS$_2$) could be predominant and facilitate mass transport at higher temperature (T). Note that Ag$_3$S$_3$ “dots” as part of a “row-dot” structure at higher S coverage where also observed. Only S adatoms were observed on Au(111).

In this contribution, we assess the kinetics of complex formation focusing on the case of S on Cu(111), and considering both formation on terraces and directly at step edges. Relevant background information is that there is an energetic preference for S to
be adsorbed at step edges rather than on terraces. With this feature in mind, it is appropriate to distinguish different regimes of the coverage, $\theta_S$, of S: (r1) very low $\theta_S$ where neither A or B type steps are saturated, so just A steps are populated; (r2) low $\theta_S$ where A steps are saturated, but not B steps which are partially populated; (r3) higher $\theta_S$ where all steps are saturated, and excess S resides on terraces. As an aside, an assessment of the degree to which steps are saturated depends not just on $\theta_S$, but also on the quality of the sample/substrate, i.e., on the step density. Only a very low $\theta_S$ is needed to saturate steps on a high-quality substrate. Evaluation of the complex formation energy mentioned above depends upon the regime. The first calculation$^{15}$ of the formation for Cu$_3$S$_3$ applied only for regime (r3), although this was not explicitly noted in that study.

In Sec. II, we extract chemical potentials for a variety of structures involving adsorbed S which can form at step edges for increasing amounts of S. These, together with the chemical potentials for complexes, lead to corresponding values of the formation energies for various complexes. Our analysis refines previous assessments. Next, in Sec. III, we address the greater challenge of assessing the kinetics of the complex formation process and its relationship to enhanced coarsening. Note that while complex formation can appear a viable candidate for enhanced surface mass transport based on assessment of surface thermodynamics (i.e., based upon the complex formation energy) and complex mobility, it may not be kinetically viable. First, we explore the kinetics for possible mechanisms of complex formation on terraces, extending previous studies to identify a new viable pathway for CuS$_2$ formation. Second, we analyze the kinetics of complex formation by detachment directly from S-decorated
step edges or structures at step edges, a previously ignored scenario which is shown to be a viable alternative to complex formation on terraces. This analysis is enabled by nudged-elastic-band determination of the minimum energy path for detachment utilizing machine-learning (ML) derived potentials for the metal-sulfur system retaining near ab-initio DFT accuracy. Conclusions are provided in Sec. IV.

II. ENERGETICS FOR STEP EDGE STRUCTURES AND $M_mS_n$ COMPLEXES

A. Sulfur chemical potentials for step edge structures and complexes

It is instructive to first introduce the sulfur chemical potential, $\mu_S$, which provides an assessment of the relative thermodynamic preference of various structures which might be formed on the surface by incorporating adsorbed S. This quantity is determined from Density Functional Theory (DFT) calculations using the VASP code with the PAW method and the PBE functional, as described in detail in previous work on these S + metal systems.\textsuperscript{20,35} We will utilize results from those studies to perform additional analysis here. The periodic computational unit cell includes a Cu substrate (which could be a perfect flat {111} surface or a stepped surface), together with an adsorbate structure involving $n \geq 1$ S atoms, and possibly $m \geq 0$ additional Cu atoms on the substrate.

For the case $m = 0$, which applies for an isolated S adatom on the Cu(111) terrace, or S decorated step edges, we introduce the quantity

$$\mu_S^* = \mu_S^*(S) = \frac{[E(S_n + \text{substrate}) - E(\text{substrate})]}{n} - E_0, \text{ for } n > 0, \quad (1)$$
where \( E(\ldots) \) denotes the total energy of the indicated system, and \( E_0 \) is a reference energy chosen here as \( \frac{1}{2} E(S_{2,\text{gas}}) \). For configurations which involve S atoms in a single configuration or local environment, \( \mu_S^* \) corresponds to the S chemical potential, \( \mu_S = \mu_S(S) \). However, for configurations with S in different environments, \( \mu_S^* \) averages over the energetics of these. In this case, an additional step is required to determine the S chemical potential, \( \mu_S \). This process is described below and in Appendix A noting that \( \mu_S \) corresponds to the differential increase in (free) energy of the system upon increasing the amount of S. For \( m > 0 \), one is typically considering adsorbed Cu-S complexes on terraces, and the S chemical potential associated with the complex is given by \(^{16,20,22}\)

\[
\mu_S(Cu_mS_n) = [E(Cu_mS_n + \text{substrate}) - E(\text{substrate}) - m \mu_{Cu}] / n - E_0, \text{ for } n > 0, \ (2)
\]

with \( E(\ldots) \) and \( E_0 \) as above, and where \( \mu_{Cu} \) denotes the energy of a Cu atom in the bulk (i.e., the negative of the bulk cohesive energy plus a Cu atom self-energy).

The highest value of \( \mu_S \) in the low S coverage regime is roughly \( \mu_S(T) = -1.91 \text{ eV} \) corresponding to isolated S adatoms on terraces \( (T) \).\(^{16}\) The lowest value of \( \mu_S \) is \( \mu_S(A) = \mu_S^*(A) = -2.24 \text{ eV} \) which is achieved for S at \{100\} micro-faceted A-type steps\(^{22}\) up to the point where such steps are saturated by a double-spaced row of S as shown in Figure 2a. Thus, \( \mu_S = -2.24 \text{ eV} \) for regime r1 with unsaturated A steps. For higher S coverages where A-type steps are fully saturated, and \{111\} micro-faceted B-type steps begin to be populated again by a double-spaced row up to saturation, i.e., regime r2, \( \mu_S \)
is given by $\mu_S(B) \approx -2.12$ eV.\textsuperscript{22} In this regime $r2$, one finds essentially identical $\mu_S$ for a double-spaced row of S forming either along the step edge or just above the step edge, as shown in Figure 2b and 2c. States in regime $r2$ with a mixture of double-spaced S at and just above the step should also have essentially the same $\mu_S \approx -2.12$ eV.

For somewhat higher amounts of S at the onset of regime $r3$, pairs of rows of S at and just above step edges form, sometimes inducing local reconstruction at the step edge.\textsuperscript{22} The latter allows S to reside at preferred four-fold hollow (4fh) sites.\textsuperscript{36} See Figure 3. Here, we determine not just $\mu_S^*$ (which averages over S in different environments), but also the chemical potential, $\mu_S$, which should be regarded as associated with the additional S atoms beyond those shown in Figure 2. For example for the A step, one has that $\mu_S^* = \frac{1}{2} [\mu_S(A) + \mu_S]$, where $\mu_S$ is associated with the additional S atoms in the row just above the step. See Appendix A for an alternative derivation. Apart from the case in Figure 3a, these $\mu_S$ are still significantly lower than $\mu_S(\mathcal{F})$, so these configurations are preferred versus populating S adatoms on terraces.

Next, consider adding further S sufficient to form triples of rows with one at and two just above the step edge (not shown). The $\mu_S$ associated with the additional S in the third row is not significantly lower than $\mu_S(\mathcal{F})$, so dispersion of the additional S on terraces is at least as favorable as these structures. However an alternative configuration for this amount of S on the surface is to form an extended Cu$_m$S$_{m+1}$ chain just above an A step.\textsuperscript{22} See Figure 4a. In this case, we can use the relation $\mu_S^* = \frac{1}{3} [\mu_S(A) + 2 \mu_S]$ to obtain the chemical potential, $\mu_S$, associated with S in the double row decorating the Cu chain. In addition, complex reconstructions with extended triangular
motifs occur at B steps generating multiple 4th sites preferred by S. See Figure 4b. We will not discuss the latter configurations further here.

The above analysis involves comparing similar chemical potentials, where it should be noted that there is some uncertainty in DFT values. However, general conclusion is that as more S is added to the surface (but still remaining in a low-coverage regime where the S population on terraces is low), both \( \mu_S^* \) and \( \mu_S \) increase towards \( \mu_S(\mathcal{F}) = -1.91 \) eV. It is also appropriate to note that STM studies by the Thiel group\(^{22} \) have directly imaged a variety of the structures described above, including the S decorated A step in Figure 2a, as well as the more exotic chains and reconstructions in Figure 4.

Finally, in Figure 5, we present the S chemical potentials, \( \mu_S(Cu_mS_n) \), for key complexes, obtained from the analysis in Ref. 20, as well as showing the configurations of these complexes.

**B. Complex formation energies**

First, we consider the scenario where the \( Cu_mS_n \) complex is formed by extracting Cu from the “bulk” (in practice from kink sites at step edges), and where the source of S will depend on the coverage regime. The formation energy for the complex on the terrace, \( E_{\text{form}}(Cu_mS_n) \), corresponds to the energy difference between the final state with the complex on the terrace and the initial state with Cu in the bulk and S in the relevant source configuration. If \( \delta E(Cu_mS_n) = E(Cu_mS_n + \text{substrate}) - E(\text{substrate}) \) denotes the total energy associated with the complex, then this formation energy satisfies\(^{16} \)
\[ E_{\text{form}}(\text{Cu}_m\text{S}_n) = \delta E(\text{Cu}_m\text{S}_n) - m \mu_{\text{Cu}} - n \delta E(\text{S}) = n[\mu_S(\text{Cu}_m\text{S}_n) - \mu_S], \]  

where again \( \mu_{\text{Cu}} \) denotes the energy of a Cu atom in the bulk, and we note that \( \mu_S = \delta E(\text{S}) - E_0 \). We emphasize that the appropriate \( \mu_S \) will depend on the source of the S, and thus on the S coverage. We note that another formulation of \( E_{\text{form}}(\text{Cu}_m\text{S}_n) \) makes explicit that this quantity is determined by the balance between the energy increase due to forming isolated Cu and S atoms on the terrace, and the energy decrease due to binding within the complex. See Appendix B. Previous analyses have always assigned \( \mu_S = \mu_S(\mathcal{J}) = -1.91 \text{ eV} \) (or a refined value for finite S coverage on terraces), but this formulation only applies in regime r3 with saturated steps and excess S on terraces.

For regime r1 with unsaturated A steps, one should select \( \mu_S = \mu_S(\mathcal{A}) = -2.24 \text{ eV} \). For regime r2 with saturated A steps but unsaturated B steps, one selects \( \mu_S = \mu_S(\mathcal{B}) \approx -2.12 \text{ eV} \). However, in regime r3 with saturated steps and excess S on terraces, one selects \( \mu_S = \mu_S(\mathcal{J}) \approx -1.91 \text{ eV} \). Values of \( E_{\text{form}}(\text{Cu}_m\text{S}_n) \) for these three regimes are summarized in Table I. For regime r3, these \( E_{\text{form}}(\text{Cu}_m\text{S}_n) \) differ somewhat from those reported in Ref. 20 where \( \mu_S \) was selected to incorporate a S coverage dependence versus the assignment here of \( \mu_S = \mu_S(\mathcal{J}) = -1.91 \text{ eV} \). Table I also reports values for diffusion barriers, \( E_d \), of complexes which will be relevant for the analysis of complex-mediated coarsening in Sec. III.

Although likely not a significant component of enhanced coarsening, one can also assess the formation of small complexes such as \( \text{CuS}_2 \) or \( \text{Cu}_2\text{S}_3 \) via detachment or extraction from extended \( \text{Cu}_m\text{S}_{m+1} \) chains (with large \( m \)) above A steps which are shown
in Figure 4a. Recall that these chains were observed in STM experiments. Contrasting the above analysis, now the source of Cu is not the bulk substrate. Results from such an analysis are presented in Appendix B.

III. ANALYSIS OF COARSENING KINETICS FOR S + Cu/Cu(111)

As indicated in Sec. I, Ostwald Ripening (OR) of a distribution of 2D monolayer Cu nanoclusters (NCs) or islands on Cu(111) involves transfer of Cu from smaller than average to larger than average islands. Thus, OR reduces the number of islands and increases their mean size, thus reducing the total island perimeter length, and thereby reduces the energy cost associated with “broken bonds” at their perimeters. The coarsening rate associated with mass carriers, C, reflects the product of the mobility of C described by a diffusion coefficient, \(D_C \sim \exp\left[-\frac{E_d(C)}{k_B T}\right]\) where \(E_d(C)\) denotes the terrace diffusion barrier for the carrier, and the equilibrium concentration or coverage of C satisfying \(\theta_{eq}(C) \sim \exp\left[-\frac{E_{form}(C)}{k_B T}\right]\) where \(E_{form}(C)\) denotes the carrier formation energy. Consequently, the effective barrier for OR has the form\(^{17,18,37}\)

\[
E_{OR}(C) = E_d(C) + E_{form}(C) + \Delta. \tag{4}
\]

We include a possible additional contribution, \(\Delta\), to account for the scenario where there is a substantial additional barrier (beyond the terrace diffusion barrier) for attachment of carriers to island edges. However, this term boosting \(E_{OR}\) only appears if the so-called attachment length, \(L_{attach} = \exp\left[\Delta/(k_B T)\right]\) (measured in lattice constants) exceeds the
mean island separation, $L_{isl}$. As an aside, we note that the barrier for detachment of a mass carrier, $c$, from step edges, $E_{\text{detach}}$, corresponds to $E_{\text{OR}}$. For a pristine Cu(111) surface, i.e., in the absence of S, the carriers are Cu adatoms, $c = \text{Cu}$, and one has that $E_d(\text{Cu}) = 0.05$ eV, $E_{\text{form}}(\text{Cu}) = 0.78$ eV,\(^{16}\) and there is no attachment barrier ($\Delta = 0$), so that $E_{\text{OR}}(\text{Cu}) = 0.83$ eV.

For a $\text{Cu}_m\text{S}_n$ complex to enhance OR, a necessary condition is that $E_{\text{OR}}(c)$ be below $E_{\text{OR}}(\text{Cu}) = 0.83$ eV. Based on this requirement, we can immediately rule out CuS and Cu$_2$S$_2$ in regime r3 based on the results in Table I. In regime r2, only CuS$_2$ can potentially enhance OR. In regime r1, no complexes can enhance OR. However, for complex formation on terraces (where $\Delta = 0$), $E_{\text{OR}}(c) < E_{\text{OR}}(\text{Cu})$ is not sufficient for the complex to enhance OR, and analysis of kinetics as presented below is required. For complex formation at step edges, $E_{\text{OR}}(c) < E_{\text{OR}}(\text{Cu})$ should be sufficient to enhance OR. However, the challenge is that now generally $\Delta > 0$, so a non-trivial analysis of the kinetics of attachment/detachment is required.

**A. Complex formation on terraces**

As noted above, the picture presented in the Sandia analysis of complex formation by extraction of Cu atoms from steps and reaction with S on terraces,\(^{14}\) is only viable in regime r3 with saturated steps and excess S on terraces (or in regime r2 for CuS$_2$). Kinetics is assessed by analysis of appropriate reaction-diffusion equations (RDEs) for Cu adatom and complex concentrations, where these equations include terms describes complex formation, terrace diffusion, and dissolution processes.\(^{5,14,17}\)
The boundary conditions for these equations specify that the concentration of Cu adatoms matches its equilibrium value at NC edges (and thus is higher at smaller NC), and also impose a zero-flux boundary condition for complex concentrations at island edges (since complexes are not formed or removed at step edges).\textsuperscript{14,17} The original Sandia study\textsuperscript{14} just utilized a simplified coupled linear pair of RDEs for the concentration of Cu atoms and of a single complex, $\mathcal{C}$. However, this particularly insightful and elegant analysis did effectively highlight the importance of a “reaction length” for $L_R \sim (D_{Cu}/k)^{1/2}$ where $D_{Cu}$ is the Cu adatom diffusion coefficient (which is far higher than that for complexes), and $k$ is a first-order reaction rate for complex formation. If $L_R > L_{isl}$ (the mean island separation), then formation of complexes is sufficiently inhibited that the quasi-uniform equilibrium concentration of complexes does not sufficiently strongly couple to gradients in the Cu adatom density to impact mass transport. It is necessary that $L_R < L_{isl}$ for enhanced transport and coarsening.

Going beyond the above simplified generic analysis, a detailed and predictive system-specific treatment of the kinetics must be based on the appropriate coupled non-linear RDEs with boundary conditions as described above. Linearization of these RDEs about spatially uniform equilibrium concentrations for various species leads to the natural emergence of reaction lengths together with explicit expressions for these lengths.\textsuperscript{5,17,37} A previous analysis following the STM observation of Cu$_2$S$_3$ complexes explored the possibility that $\mathcal{C} = $ Cu$_2$S$_3$, formed by the reaction Cu + CuS$_3$ $\rightarrow$ Cu$_2$S$_3$, could enhance mass transport.\textsuperscript{16} However, the corresponding reaction length far exceeds $L_{isl}$, so this does not appear to be a viable mechanism for enhanced OR.
Thus, we consider an alternative pathway for enhanced OR in which CuS$_2$ dominates mass transport, and where CuS$_2$ is formed on terraces via the tri-molecular reaction, Cu + S + S → CuS$_2$. In this case the appropriate non-linear RDE for the surface concentrations or coverages ($\theta$), of Cu adatoms and CuS$_2$ are

$$\frac{\partial}{\partial t} \theta_{\text{Cu}} = D_{\text{Cu}} \nabla^2 \theta_{\text{Cu}} - F(\text{Cu} + S + S) + R(\text{Cu} + S + S) + ... \approx 0, \text{ and}$$

$$\frac{\partial}{\partial t} \theta_{\text{CuS}_2} = D_{\text{CuS}_2} \nabla^2 \theta_{\text{CuS}_2} + F(\text{Cu} + S + S) - R(\text{Cu} + S + S) + ... \approx 0. \text{ (6)}$$

Here, $F(\text{Cu} + S + S)$ denotes the rate for diffusion-mediated formation of CuS$_2$, and $R(\text{Cu} + S + S)$ denoting the rate of dissociation of CuS$_2$, are given by

$$F(\text{Cu} + S + S) = (D_{\text{Cu}} + D_{\text{S}}) \theta_{\text{Cu}} (\theta_{\text{S}})^2, \text{ and}$$

$$R(\text{Cu} + S + S) = (D_{\text{Cu}} + D_{\text{S}}) \exp[-E_{\text{bind}}(\text{CuS}_2)/(k_B T)] \theta_{\text{CuS}_2}, \text{ (8)}$$

where $E_{\text{bind}}(\text{CuS}_2) > 0$ is the binding energy strength for adsorbed CuS$_2$ (i.e., the difference in energy between Cu and S dispersed on the terrace and incorporated in CuS$_2$). This rate selection appropriately satisfies detailed-balance. Given that in regime r3, one has

$$E_{\text{form}}(\text{CuS}_2) = E_{\text{form}}(\text{Cu}) - E_{\text{bind}}(\text{CuS}_2) \text{ (9)}$$
(see Appendix B), equating F() and R() correctly recovers the equilibrium concentration
\[ \theta_{\text{CuS}_2}\text{(equil)} = \exp[-E_{\text{form}}(\text{CuS}_2)/(k_BT)] \ (\theta_S)^2. \]
Other possible reaction paths leading to formation and removal of Cu and CuS_2 are left implicit in (5) and (6).

As indicated above, these non-linear equations are linearized for small deviations about spatially uniform equilibrium concentrations. Setting \( \theta_{\text{Cu}} = \theta_{\text{Cu}}\text{(equil)} + \delta \theta_{\text{Cu}} \) and
\[ \theta_{\text{CuS}_2} = \theta_{\text{CuS}_2}\text{(equil)} + \delta \theta_{\text{CuS}_2}, \]
from (5) one obtains the linearized equation

\[ \partial / \partial t \delta \theta_{\text{Cu}} = D_{\text{Cu}} \nabla^2 \delta \theta_{\text{Cu}} - k(\text{Cu}+S+S) \delta \theta_{\text{Cu}} +... \approx 0, \quad (10) \]

with \( k(\text{Cu}+S+S) = (D_{\text{Cu}} + D_S) \ (\theta_S)^2. \) As noted above the activation barrier for terrace diffusion of Cu is \( E_d(\text{Cu}) = 0.05 \text{ eV}. \) Our separate calculations for S adatoms show that \( E_d(S) = 0.15 \text{ eV} \) (from DFT using the PBE functional with a 2\texttimes{}2 lateral supercell and the Cu\{111\} surface represented by a 3 layer slab), in reasonable agreement with a previous estimate\(^{38} \) of \( E_d(S) = 0.17 \text{ eV}. \) Thus, one has that \( D_{\text{Cu}} \gg D_S, \) and consequently that the relevant reaction length is given by \( L_R \approx 1/\theta_S \) (in lattice constants for \( \theta_S \) in monolayers). For \( \theta_S = (5-20)\times10^{-3} \) monolayers, \( L_R \) is well below \( L_{isl} \) in experiments.\(^5 \) The feature that (10) has solutions for \( \delta \theta_{\text{Cu}} \) vary exponentially in space with decay length \( L_R \lesssim L_{isl} \) demonstrates that there is sufficiently strong coupling of the Cu adatom concentration to that for CuS_2 complexes to induce complex-enhanced Cu mass transport. Thus, enhancement via this mechanism is operative for both regime r3 where \( E_{\text{OR}}(\text{CuS}_2) = 0.19 \text{ eV}, \) and for regime r2 where \( E_{\text{OR}}(\text{CuS}_2) = 0.61 \text{ eV} \) (versus \( E_{\text{OR}}(\text{Cu}) = 0.83 \text{ eV} \)).
B. Complex formation directly at steps

There has been no previous analysis of the possible direct formation of complexes at step edges, which specifically aims to assess if such a mechanism can lead to enhanced OR. The challenge is to identify viable pathways for formation and detachment in what is a multi-dimensional phase space of possible configurations at step edges, and to determine the minimum energy path ( MEP) and thus the barrier for such detachment processes. An additional complication is the large number of Cu-sulfur structures and reconstructions which can occur at step edges, and which could provide potential sources for complexes, at least in regime r3.

First, we observe that such direct formation of complexes, $\mathcal{C}$, as a pathway for enhanced OR not possible in regime r1 since $E_{\text{OR}}(\mathcal{C})$ is no smaller than $E_d(\mathcal{C}) + E_{\text{form}}(\mathcal{C})$ for which values exceed $E_{\text{OR}}(\text{Cu})$ for all complexes $\mathcal{C}$. Such enhancement is plausible in regime r2 for $\mathcal{C} = \text{CuS}_2$, but perhaps unlikely given the possibility of a significant extra barrier for detachment, $\Delta$. Thus, we focus on regime r3 where the higher S chemical potential, and the above mentioned diversity of Cu-sulfur step edge structures, as well as the significant population of S on terraces, should facilitate formation of various complexes, $\mathcal{C}$, with $E_{\text{OR}}(\mathcal{C}) < E_{\text{OR}}(\text{Cu})$.

Given the vast phase space of possible complex formation and detachment pathways, comprehensive exploration at the level of DFT determining MEPs with low barriers is inefficient due to the computational demand. However, there have been significant recent advances in the use of Machine Learning (ML) strategies to develop force fields retaining high-level near-DFT accuracy.$^{39,40}$ In implementing this approach,
we have performed Ab-Initio Molecular Dynamics (AIMD) simulations of the dynamics of Cu nanoparticles with 60 to 1000 Cu atoms and with various amounts of adsorbed S, and also of copper sulfide nanoparticles. The S + Cu(111) system was also simulated mostly for purposes of validation, and it only contributed to a small part of the training set data. This data, which contains information about how energies and forces depend on atomic coordinates, is then used to train a set of ML potentials. We utilize the DeepMD-tool kit\textsuperscript{41} due to its ease-of-use and efficiency. With these potentials, e.g., MD simulation can be performed for much longer times than in AIMD. In our case, much more efficient and extensive Nudge Elastic Band (NEB) analysis\textsuperscript{42} can be performed to determine MEPs for complex formation and detachment. In a separate contribution, we will describe in more detail the development of these potentials, and also present extensive MD simulations to probe dynamics at step edges in the S + Cu(111) system.

Here, we just perform a limited but targeted analysis to provide a proof-of-principle demonstration that complexes can be formed directly at or near step edges with a sufficiently low barrier to facilitate enhanced OR. We focus on two cases: (i) detachment of CuS\textsubscript{2} from kink sites at a S-decorated B step; and (ii) detachment of CuS\textsubscript{2} from extended Cu\textsubscript{m}S\textsubscript{m+1} chains just above A steps.

For formation and detachment of complexes at step edges, one naturally anticipates that this process is facilitated at kink sites where the Cu has a lower coordination and thus is more readily extracted. Thus, in Figure 6, we show one such example of CuS\textsubscript{2} formation at a kink site on a S-decorated B step, which is facilitated by an additional pair of nearby S adatoms on the terrace. As we are considering regime r3, the population of such terrace S adatoms is non-negligible. The detachment pathway
involves the relatively mobile Cu atom starting at the kink site being passed between relative immobile nearby S adatoms to eventually form a CuS$_2$ complex on the terrace by inserting itself between the two terrace S adatoms. For this process, the detachment barrier is only $E_{\text{detach}}(\text{CuS}_2) = 0.43$ eV as shown in Figure 7, well below $E_{\text{OR}}(\text{Cu})$, so it should facilitate enhanced OR. It is interesting to note the formation of a CuS$_3$ type motif around the transition state of the detachment process. Note that as is appropriate, the difference between the final and initial energies of the MEP roughly corresponds to the DFT estimate of the formation energy for CuS$_2$ in regime r3. A couple of additional comments are appropriate. First, the energetics of detachment is primarily controlled by the two S atoms at the kink site and the two terrace S atoms, and thus does not change dramatically if the other 3 S adatoms in Figure 7 are absent. Second, our analysis of the analogous detachment process at a kink site on an A step yields a significantly higher barrier. This is perhaps not surprising as S adatoms are more stable at the A step than at the B step.

Next, we consider the formation and detachment of complexes by extraction from extended Cu$_m$S$_{m+1}$ chains above A steps aided by terrace S adatoms, where we explore only the case of CuS$_2$ formation. One might naturally first consider detachment from the end of the chain. However, effective NEB analysis requires judicious initial appropriate placement of the terrace S adatoms, and an appropriate selection (of the many possible choices) is not obvious. Thus, here we just consider the process of extraction CuS$_2$ from the middle of an extended Cu$_x$S$_{x+1}$ chain where an initial appropriate placement of the terrace S adatoms is more clear. In Figure 8, we show one such example of this process facilitated by a pair of nearby S adatoms on the terrace, as is reasonable in
regime r3. Analogous to detachment from a kink site at a step edge, the pathway involves passing a relatively mobile Cu atom between relative immobile nearby S adatoms. The MEP shown in Figure 9 suggests a detachment barrier of $\Delta E(CuS_2) = 0.48$ eV. However, our separate analysis based on the same ML generated potential reveals that there is significant repulsion of about $E_{\text{rep}} = 0.11$ eV between the terrace and chain S in the initial configuration. Thus, starting with terrace S further from the chain would lower the initial energy on the MEP by $E_{\text{rep}}$ and boost the detachment barrier to $E_{\text{detach}}(CuS_2) = E_{\text{rep}} + \Delta E = 0.59$ eV, still significantly below $E_{OR}(Cu)$.

Detailed analysis of coarsening kinetics for the mechanism involving direct detachment of complexes from step edges of nanoclusters would be based upon conventional diffusion equations for complex concentrations (analogous to classic OR treatment which applies for coarsening of islands on S-free metal(111) surfaces). In contrast to the S-free case where the Cu concentration matches its equilibrium value at step edges, now the boundary conditions on the complex concentration reflects the presence of any additional attachment barriers. Thus, the process can be attachment-limited versus diffusion-limited (which applies when Cu adatoms are mass carriers). The boundary conditions should also reflect the feature than the Cu chemical potential is slightly higher at the edge of smaller islands, and this should induce slightly lower detachment barriers than for larger islands. One other complication is that there can be numerous energetically similar detachment pathways involving different arrangements of S adatoms at the step edge and nearby on the terrace. Thus, determination of the prefactor for the detachment rate, which could exceed typical values, is non-trivial.
For complex formation via detachment from linear Cu$_m$S$_{m+1}$ chains, it is less clear whether this process can effectively contribute to coarsening since the chemical potential of Cu in such chains should be independent of whether they are adjacent to the step edges of large or small Cu islands. If the S concentration is slightly higher at smaller islands, this feature could boost the detachment rate.

5. CONCLUSIONS

Coarsening of supported metal nanoclusters is a phenomenon of fundamental interest, but also of importance for applications including understanding of catalyst degradation. Of particular interest is the effect of non-metallic chemisorbed species which are likely present for most applications under “operating conditions”. In particular, it has been suggested that coarsening, and more generally surface mass transport, can be enhanced due to the formation of adsorbed complexes incorporating these chemisorbed species and metal atoms. This idea has been proposed for complex catalytic systems involving 3D metal nanoclusters on non-metallic supports, and well as for chemisorption onto low-index metal surfaces supporting 2D homoepitaxial nanoclusters. The latter class of systems provides the opportunity for development of a fundamental understanding and characterization of such enhanced coarsening processes. For S chemisorbed on coinage metal surfaces, following a study by the Sandia group for S/Cu(111), the Thiel group together with theoretical collaborators undertook a systematic study of this entire class of systems. A general goal was to provide a broad set of observations of behavior in different systems which could
underpin a general understanding of requirements for enhanced coarsening. A specific goal was to provide definitive experimental imaging of adsorbed metal-sulfur complexes to validate their existence at least in some systems. These goals were achieved in an extensive series of publications\textsuperscript{16-36} providing a sound framework for analysis of enhanced coarsening in these systems.

The default paradigm for enhanced coarsening for S on metal surfaces is that complex formation occurs by extraction of metal atoms from the edges of nanoclusters and their reaction with excess S adatoms on terraces.\textsuperscript{14} While this is often plausible from a thermodynamic perspective, an appropriate analysis of the kinetics had not yet demonstrated viability for any specific system. However, such an analysis was achieved here for S on Cu(111), specifically demonstrating that coarsening could be enhanced by formation of CuS \textsubscript{2} via a tri-molecular reaction Cu + S + S \rightarrow CuS \textsubscript{2}. In addition, we introduce a new paradigm of direct formation of complexes at the step edges of nanoclusters. We demonstrate that this is a viable mechanism for enhanced coarsening. Aided by reliable ML-derived potentials for the Cu-S system, we perform a NEB analysis of the MEP for the formation and detachment process for CuS \textsubscript{2} aided by nearby terrace S. This analysis does find scenarios where the barrier for this process is not prohibitive, at least when there is a significant population of terrace S.

We have noted in Introduction that our previous studies suggested the particular stability of linear S-Cu-S motifs, either as isolated CuS \textsubscript{2} complexes or as components of larger complexes or chains. The feature that CuS \textsubscript{2} is identified in this study as a natural candidate to enhance OR is compatible with this view. An alternative supporting
perspective on the relevant energetics of CuS\(_2\) and other Cu\(_m\)S\(_n\) complexes is provided in Appendix C utilizing a many-body cluster expansion for lateral interactions.\(^{43}\)

Finally, we remark that for the observed enhanced coarsening in S + Ag(111),\(^{17}\) and similar picture to for S + Cu(111) is plausible. The mechanism Ag + S + S \(\rightarrow\) AgS\(_2\) on terraces should be effective in enhancing OR. Plausibly, complex formation via direct detachment from S-decorated step edges can also enhance OR.

**ACKNOWLEDGEMENTS**

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The authors have no conflicts to disclose.

**DATA AVAILABILITY**

The data that support the findings of this study are available within the article and from the authors upon reasonable request.

**APPENDIX A: S CHEMICAL POTENTIALS FOR STEP EDGE STRUCTURES**
The S chemical potential satisfies \( \mu_S = \partial F / \partial N_S \) where \( F \) is the free energy of the system (approximated here as the total energy, \( E \)), and \( N_S \) is the number of S adatoms. For A steps decorated by one double-spaced row of S adatoms (regime r1), we neglect interactions between the S. Then, the system energy will vary linearly with the number of S at the step, and for convenience \( \mu_S \) is determined from the configuration in Fig. 2a where the step is fully populated (i.e., saturated) by S. Increasing the amount of S to reach regime r2, again the system energy again varies linearly with the number of additional S incorporated at B steps to form double-spaced row. The rate of variation (i.e., the chemical potential) is different than in regime r1 due to the different local environment of S adatoms. For convenience, \( \mu_S \) is determined from the configuration in Fig. 2b or 2c where the step is fully populated by a double-spaced row of S either at or above the step.

At the onset of regime r3 for the scenario shown in Fig. 3b or 3c, a second row of double-spaced S adatoms begins to form just above reconstructed A or B steps. Consider determination of \( \mu_S \) associated with population of the row of S adatoms just above the reconstructed A step. In Sec. II, we have used the configuration in Fig. 3b with a complete double-spaced row both at and above the step to evaluate the chemical potential \( \mu_S \) from \( \mu_S^* = \frac{1}{2} [\mu_S(A) + \mu_S] \). A derivation of this result based upon the relation \( \mu_S = \partial F / \partial N_S \) follows. Consider an A step of fixed length, \( L_A \), in lattice constants which is fully populated by a double-spaced row of \( N_S^+ \) S adatoms at the step, and partially populated by a shorter double-spaced row of \( N_S^+ \) S adatoms just above the step. Then, one has \( N_S = N_S^+ + N_S^- \) with \( N_S^+ < N_S^- \) where \( N_S^- = \frac{1}{2} L_A \) is fixed. This configuration has:

(i) a portion with a pair of double-spaced rows each with \( N_S^+ \) S atoms at and above the
step edge associated with mean chemical potential \( \mu_S^* \); and (ii) a portion with a single double-spaced row of \( Ns^- \cdot Ns^+ \) S atoms at the step edge associated with chemical potential \( \mu_S(A) \). Thus, it follows that

\[
F = 2 \ Ns^+ \ \mu_S^* + (Ns^- - Ns^+) \ \mu_S(A),
\]

which recovers the above relation involving \( \mu_S \) noting that

\[
\mu_S = \frac{\partial F}{\partial Ns} = \frac{\partial F}{\partial Ns^+} = 2 \mu_S^* - \mu_S(A).
\]

A similar analysis applies for \( \mu_S \) in other configurations such as that in Fig. 4a.

**APPENDIX B: COMPLEX FORMATION ENERGIES**

**First,** consider the formation of complexes on terraces where Cu atoms are extracted from the bulk. We define \( \delta E(X) = E(X + \text{substrate}) - E(\text{substrate}) \) corresponding to the total energy associated with an adsorbed species, \( X \), which includes the self-energy of the constituent atoms. Then, the total “surface atomization” or binding energy strength \( E_{\text{bind}}(\text{Cu}_m\text{S}_n) > 0 \) of Cu and S atoms within the complex is given by \(^{20}\)

\[
E_{\text{bind}}(\text{Cu}_m\text{S}_n) = m \ \delta E(\text{Cu}_{\text{ads}}) + n \ \delta E(\text{S}_{\text{ads}}) - \delta E(\text{Cu}_m\text{S}_n),
\]
where Cu$_{\text{ads}}$ and S$_{\text{ads}}$ denote isolated adsorbed atoms on terraces. Formation energies for Cu and S adatoms on terraces (where Cu is extracted from the bulk) are given by

$$E_{\text{form}}(\text{Cu}) = \delta E(\text{Cu}_{\text{ads}}) - \mu_{\text{Cu}}, \text{ and } E_{\text{form}}(\text{S}) = \delta E(\text{S}_{\text{ads}}) - \delta E(\text{S}),$$

(14)

respectively. Here, $\mu_{\text{Cu}}$ denotes the total energy of bulk Cu, and $\delta E(\text{S})$ depends on the source of S. For example, $E_{\text{form}}(\text{S}) = 0$ where the source of S is on the terrace, but $E_{\text{form}}(\text{S}) > 0$ for where the source of S is at unsaturated steps. Then, since the formation energy for the Cu$_m$S$_n$ complex on terraces by extraction of Cu from the bulk satisfies

$$E_{\text{form}}(\text{Cu}_m\text{S}_n) = \delta E(\text{Cu}_m\text{S}_n) - m \mu_{\text{Cu}} - n \delta E(\text{S}),$$

it follows that

$$E_{\text{form}}(\text{Cu}_m\text{S}_n) = -E_{\text{bind}}(\text{Cu}_m\text{S}_n) + m E_{\text{form}}(\text{Cu}) + n E_{\text{form}}(\text{S}).$$

(15)

Thus, $E_{\text{form}}(\text{Cu}_m\text{S}_n)$ is determined by the balance between the energy decrease due to binding within the complex, and the energy increase due to forming isolated Cu and S atoms on the terrace.

Second, consider the formation of small complexes such as CuS$_2$ and Cu$_2$S$_3$ via extraction from an extended Cu$_m$S$_{m+1}$ chain for large m. From the definition of the S chemical potential $\mu_S(\text{Cu}_m\text{S}_{m+1}) = \mu_S(\text{chain})$ for the extended chain, which will be independent of large m, it follows from (2) that

$$\delta E(\text{Cu}_m\text{S}_{m+1}) = (m+1) \mu_S(\text{chain}) + (m+1) E_0 + m \mu_{\text{Cu}}.$$  

(16)
We will also use that $\delta E(S) = \mu_S + E_0$ and select $\mu_S = \mu_S(\mathcal{J}) \approx -1.91$ eV and $\mu_S(\text{chain}) = -1.85$ eV below. For extraction of CuS$_2$ from the end of the chain, via the mechanism
\[ \text{Cu}_{m+1}S + S \rightarrow \text{Cu}_{m-1}S + \text{CuS}_2, \]
the formation satisfies
\[
E_{\text{form}}(\text{CuS}_2|\text{chain end}) = \delta E(\text{Cu}_{m-1}S) + \delta E(\text{CuS}_2) - \delta E(\text{Cu}_{m}S_{m+1}) - \delta E(S)
\]
\[ = 2 \mu_S(\text{CuS}_2) - \mu_S - \mu_S(\text{chain}) = 0.08 \text{ eV}. \quad (17) \]

For extraction from the interior of the chain via the mechanism
\[ \text{Cu}_{m+m'}S_{m+m'+1} + 2S \rightarrow \text{Cu}_{m-1}S + \text{CuS}_2 + \text{Cu}_{m}S_{m'+1}, \]
the formation satisfies
\[
E_{\text{form}}(\text{CuS}_2|\text{chain interior})
\]
\[ = \delta E(\text{Cu}_{m-1}S) + \delta E(\text{CuS}_2) + \delta E(\text{Cu}_{m}S_{m'+1}) - \delta E(\text{Cu}_{m+m'}S_{m+m'+1}) - 2\delta E(S)
\]
\[ = 2 \mu_S(\text{CuS}_2) - 2\mu_S = 0.14 \text{ eV}. \quad (18) \]

**APPENDIX C: CLUSTER EXPANSION FOR Cu$_m$S$_n$ ENERGETICS**

A perspective on the energetics of Cu$_m$S$_n$ complexes follows from application of a many-body cluster expansion commonly used in lattice-gas models for chemisorbed species.\textsuperscript{43} Given the presumed particular stability of linear S-Cu-S motifs, it is natural to decompose the total energy of complexes as the sum over: (i) an attractive pair
interaction of strength \( \phi_{\text{CuS}} > 0 \) for each neighboring Cu-S pair; (ii) an attractive trio interaction of strength \( \phi_{\text{SCuS}} > 0 \) for each linear S-Cu-S unit; and (iii) an attractive contribution of strength \( \phi_{\text{CuCu}} > 0 \) for each nearest-neighbor (NN) pair of Cu adatoms. Within this model, binding energy strengths are given by

\[
E_{\text{bind}}(\text{CuS}) = \phi_{\text{CuS}}, \quad E_{\text{bind}}(\text{CuS}_2) = 2\phi_{\text{CuS}} + \phi_{\text{SCuS}}.
\]

(19)

and \( E_{\text{bind}}(\text{Cu}_2\text{S}_3) = \phi_{\text{CuCu}} + 4\phi_{\text{CuS}} + 2\phi_{\text{SCuS}}. \)

To obtain DFT values of these quantities, we use the relation \( E_{\text{bind}}(\text{Cu}_m\text{S}_n) = -E_{\text{form}}(\text{Cu}_m\text{S}_n) + m E_{\text{form}}(\text{Cu}) \), with the DFT value of \( E_{\text{form}}(\text{Cu}) = 0.78 \) eV. Then, from Table I for regime r3, we obtain \( E_{\text{bind}}(\text{CuS}) = 0.12 \) eV, \( E_{\text{bind}}(\text{CuS}_2) = 0.64 \) eV, and \( E_{\text{bind}}(\text{Cu}_2\text{S}_3) = 1.53 \) eV. Then (19) provides 3 equations for the 3 unknown interaction parameters, solution of which yields

\[
\phi_{\text{CuS}} = 0.12 \text{ eV}, \quad \phi_{\text{SCuS}} = 0.40 \text{ eV}, \quad \text{and} \quad \phi_{\text{SCuS}} = 0.25 \text{ eV}.
\]

(20)

These values are reasonable, the large value of \( \phi_{\text{SCuS}} \) being consistent with the perceived stability of linear S-Cu-S motifs. Also, the value of \( \phi_{\text{SCuS}} \) is reasonably consistent with the DFT value of \( E_{\text{form}}(\text{Cu}) \) which should correspond to \( 3\phi_{\text{SCuS}}. \)

With these energetic parameters, the model predicts a large value for

\[
E_{\text{bind}}(\text{Cu}_3\text{S}_3) = 3\phi_{\text{CuCu}} + 6\phi_{\text{CuS}} + 3\phi_{\text{SCuS}} = 2.67 \text{ eV}
\]

(21)
reflecting in part the multiple S-Cu-S motifs in Cu$_3$S$_3$ (cf. the DFT value of 2.13 eV), and
much lower values for

\[ E_{\text{bind}}(\text{CuS}_3) = +3\phi_{\text{CuS}} = 0.36 \text{ eV} \quad \text{and} \quad E_{\text{bind}}(\text{Cu}_2\text{S}_2) = +4\phi_{\text{CuS}} + \phi_{\text{CuCu}} = 0.73 \text{ eV}, \quad (22) \]

noting the lack of linear S-Cu-S motifs (cf. DFT values of 0.56 eV and 0.58 eV, respectively).

REFERENCES


TABLES

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Table I. Values for $E_{\text{form}}(Cu_mS_n)$ in eV for three distinct S coverage regimes. We also show value of the complex diffusion barriers, $E_d(Cu_mS_n)$ in eV, from Ref. 18 for CuS<sub>2</sub>, and Ref. 16 for other complexes, which will be utilized in Sec. III. The formation energy for Cu adatoms is 0.78 eV.

FIGURE CAPTIONS

Figure 1. Images of former Thiel group PhD students who analyzed behavior of chalcogens adsorbed on coinage metal surfaces, together with that of their advisor.  

Figure 2. Sulfur chemical potentials, $\mu_S$, for: (a) the low coverage regime r1 for S at an A step; and (b,c) regime r2 for S at B steps. Cu on the lower (upper) terrace are grey (white); S atoms are yellow.

Figure 3. Sulfur chemical potentials, $\mu_S^*$, averaged over two types of S for the onset of regime r3 for S at: (a,b) A steps; and (c,d) B steps. Also shown is the chemical potential $\mu_S$ associated with the additional S (relative to those in Fig. 2a and 2b) just above the step.
Figure 4. (a) $\mu^*$ and $\mu_S$ for an extended $\text{Cu}_m\text{S}_{m+1}$ chain just above an A step; Cu on the upper terrace are denote by blue circles; (b) substantial S-induced reconstruction at B steps leading to the formation of 4-fold hollow adsorption sites for S.

Figure 5. Configurations and S chemical potentials, $\mu_S(\text{Cu}_m\text{S}_n)$, in eV for various adsorbed complexes $\text{Cu}_m\text{S}_n$.

Figure 6. Images (a-j) from NEB analysis of detachment of CuS$_2$ from a kink site at an S-decorated B step aided by two terrace S. NEB image numbers are shown (0: initial; 12: final) corresponding to the MEP shown in Fig. 7. The red $\times$ tracks the Cu atom which becomes incorporated in CuS$_2$.

Figure 7. NEB results for the MEP for detachment of CuS$_2$ from a kink site at an S-decorated B step, a process aided by two terrace S.

Figure 8. Images (a-f) from NEB analysis of extraction of CuS$_2$ from an extended $\text{Cu}_m\text{S}_{m+1}$ chain above an A step aided by two terrace S. NEB image numbers are shown (0: initial; 12: final) corresponding to the MEP shown in Fig. 9. The red $\times$ tracks the Cu atom which becomes incorporated in CuS$_2$.

Figure 9. NEB results for the MEP for extraction of CuS$_2$ from an extended $\text{Cu}_x\text{S}_{x+1}$ chain above an A step, a process aided by two terrace S.
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